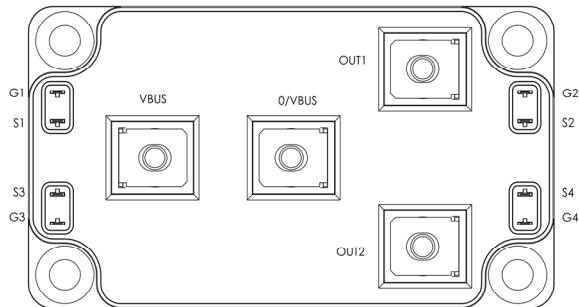
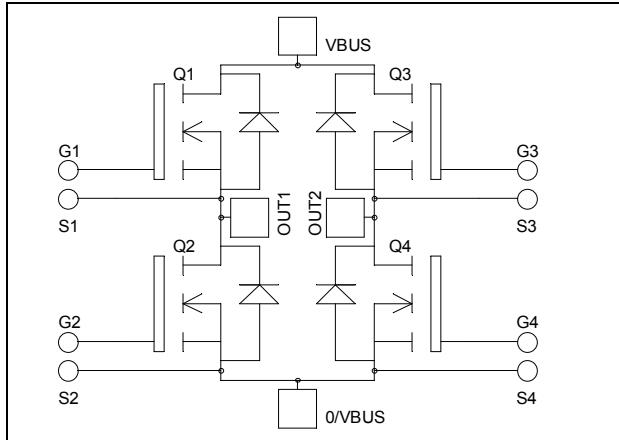


**Full - Bridge  
MOSFET Power Module**

$V_{DSS} = 1200V$   
 $R_{DSon} = 290m\Omega$  typ @  $T_j = 25^\circ C$   
 $I_D = 34A$  @  $T_c = 25^\circ C$


**Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

**Features**

- Power MOS 7® FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

**Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

**Absolute maximum ratings**

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	1200	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
$I_{DM}$	Pulsed Drain current	136	
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	348	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)	22	A
$E_{AR}$	Repetitive Avalanche Energy	50	$mJ$
$E_{AS}$	Single Pulse Avalanche Energy	3000	

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0\text{V}, V_{DS} = 1200\text{V}$	$T_j = 25^\circ\text{C}$		350	$\mu\text{A}$
		$V_{GS} = 0\text{V}, V_{DS} = 1000\text{V}$	$T_j = 125^\circ\text{C}$		1500	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10\text{V}, I_D = 17\text{A}$		290	348	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5\text{mA}$	3		5	$\text{V}$
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{V}$			$\pm 150$	$\text{nA}$

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$		10.3		$\text{nF}$
$C_{oss}$	Output Capacitance			1.54		
$C_{rss}$	Reverse Transfer Capacitance			0.26		
$Q_g$	Total gate Charge	$V_{GS} = 10\text{V}$ $V_{Bus} = 600\text{V}$ $I_D = 34\text{A}$		374		$\text{nC}$
$Q_{gs}$	Gate – Source Charge			48		
$Q_{gd}$	Gate – Drain Charge			240		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ 125°C</b> $V_{GS} = 15\text{V}$ $V_{Bus} = 800\text{V}$ $I_D = 34\text{A}$ $R_G = 2.5\Omega$		20		$\text{ns}$
$T_r$	Rise Time			15		
$T_{d(off)}$	Turn-off Delay Time			160		
$T_f$	Fall Time			45		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 15\text{V}, V_{Bus} = 800\text{V}$ $I_D = 34\text{A}, R_G = 2.5\Omega$		1980		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			1371		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 15\text{V}, V_{Bus} = 800\text{V}$ $I_D = 34\text{A}, R_G = 2.5\Omega$		3131		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			1714		

**Source - Drain diode ratings and characteristics**

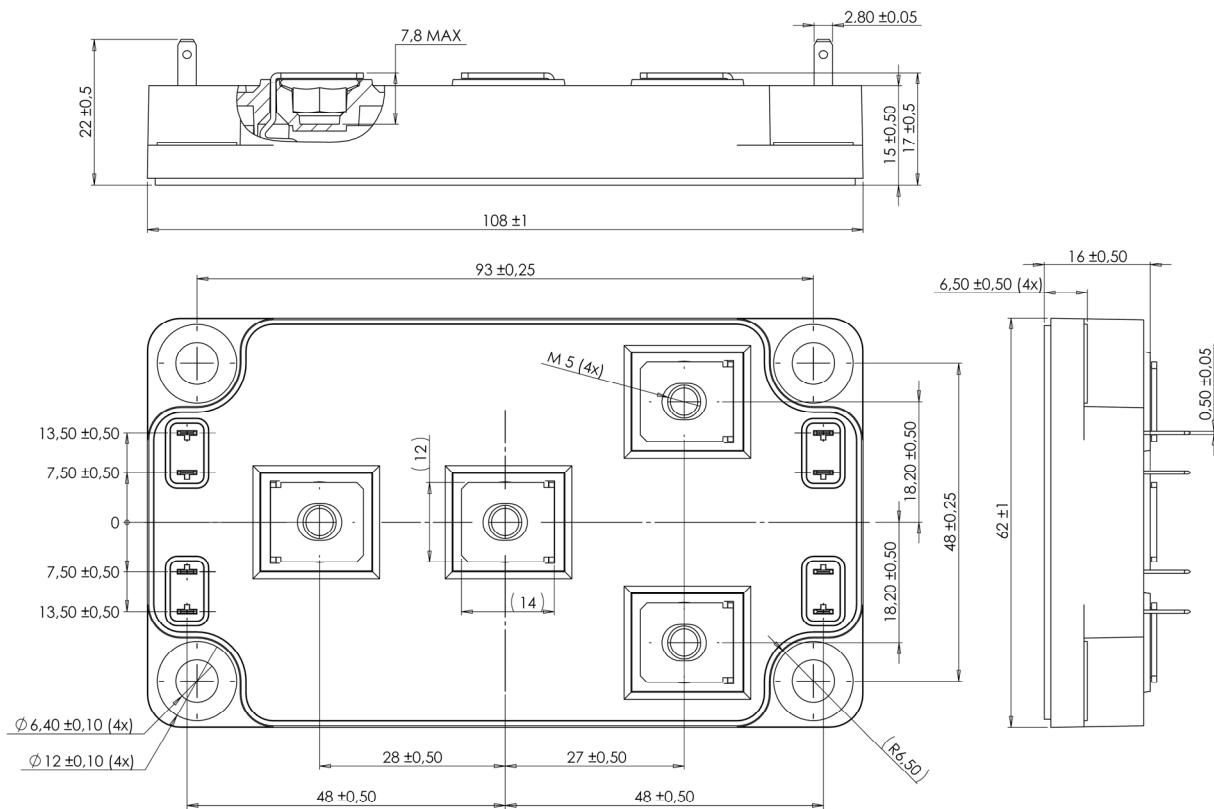
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_S$	Continuous Source current (Body diode)		$T_c = 25^\circ\text{C}$		34	$\text{A}$
			$T_c = 80^\circ\text{C}$		25	
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0\text{V}, I_S = - 34\text{A}$			1.3	$\text{V}$
$dv/dt$	Peak Diode Recovery ①				18	$\text{V/ns}$
$t_{rr}$	Reverse Recovery Time	$I_S = - 34\text{A}$ $V_R = 600\text{V}$ $di_S/dt = 200\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		320	$\text{ns}$
			$T_j = 125^\circ\text{C}$		650	
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$	4		$\mu\text{C}$
			$T_j = 125^\circ\text{C}$	14		

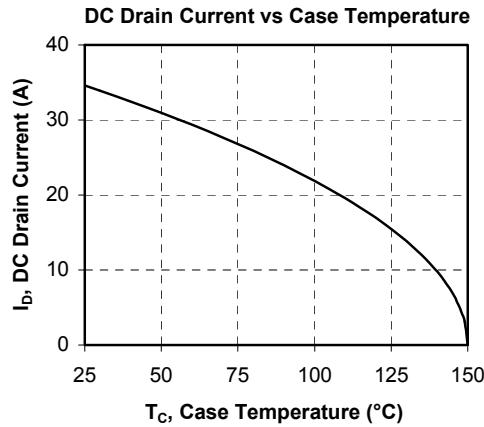
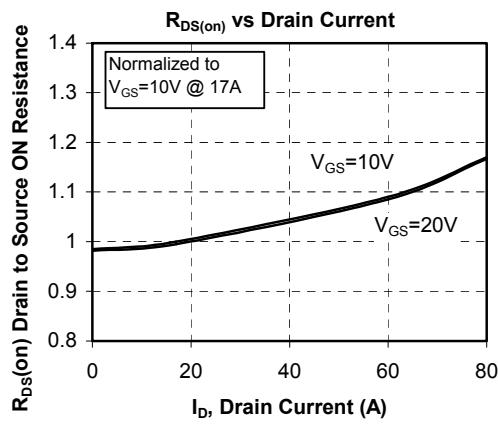
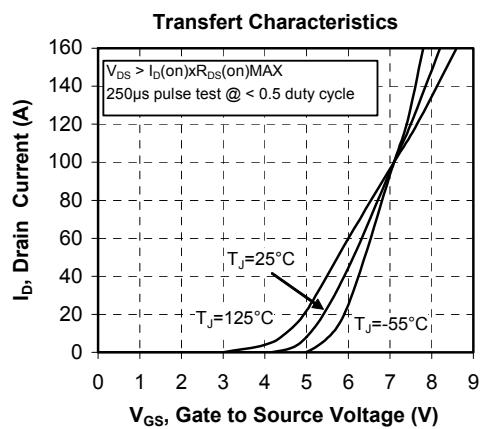
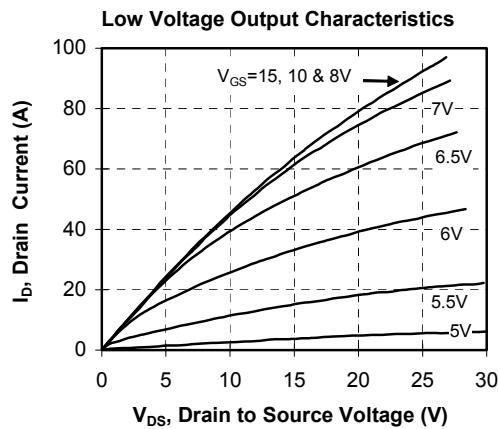
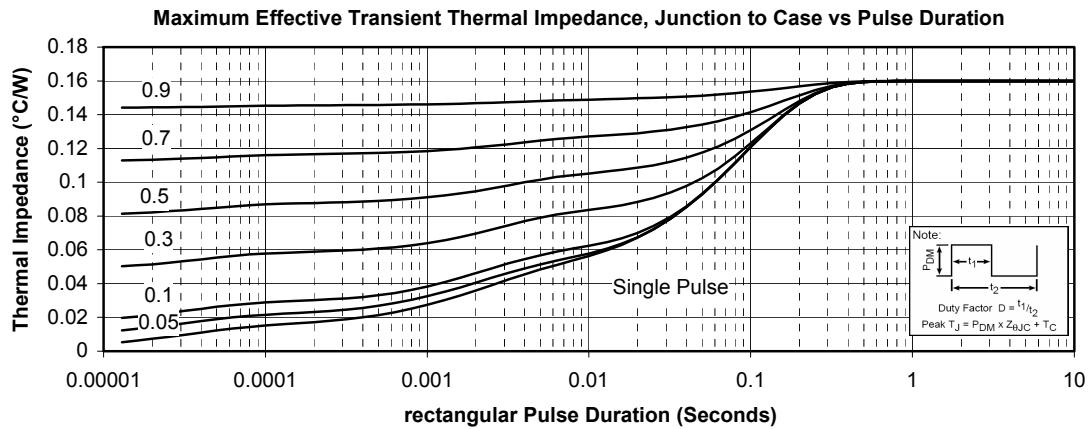
 ①  $dv/dt$  numbers reflect the limitations of the circuit rather than the device itself.

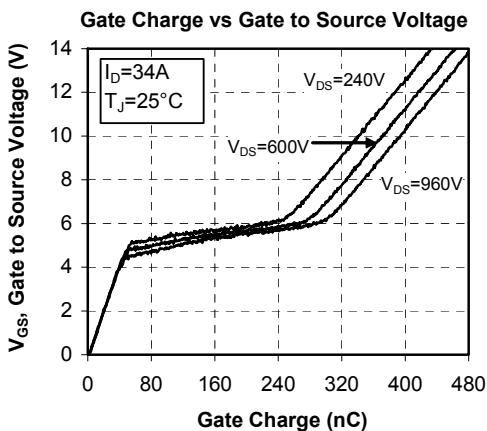
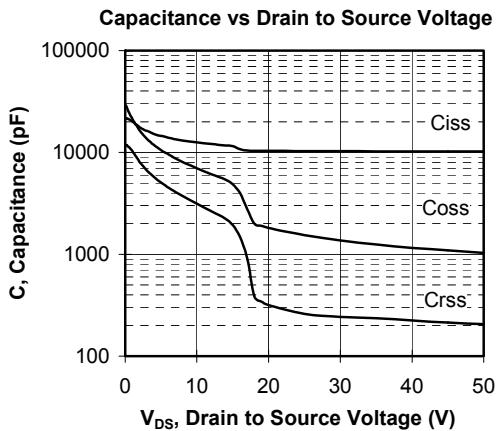
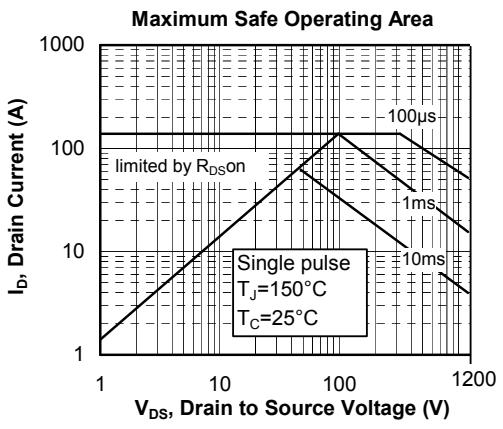
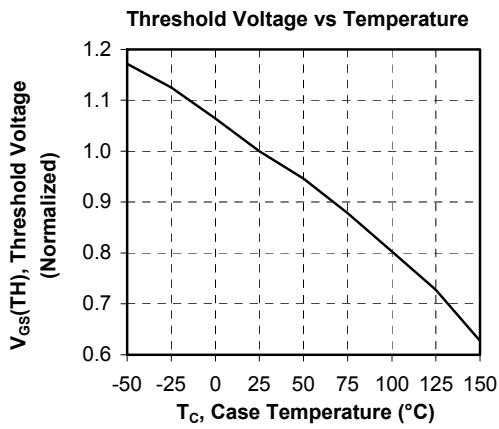
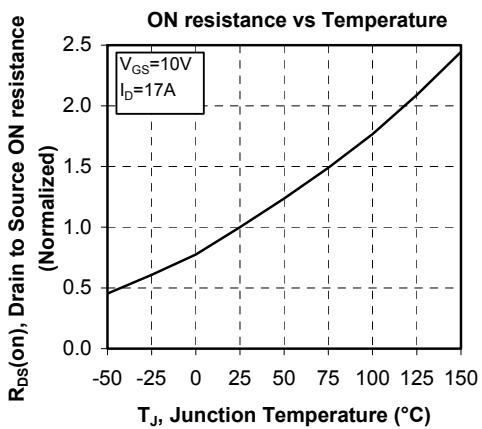
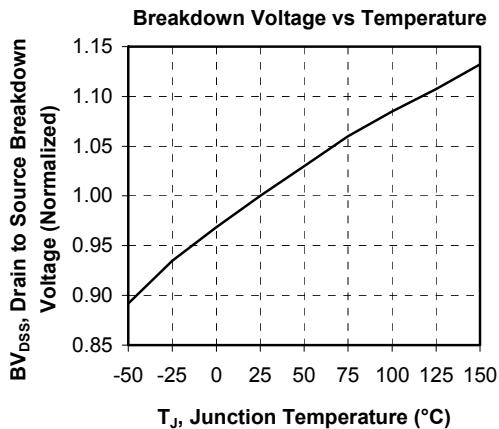
 $I_S \leq - 34\text{A}$     $di/dt \leq 700\text{A}/\mu\text{s}$     $V_R \leq V_{DSS}$     $T_j \leq 150^\circ\text{C}$

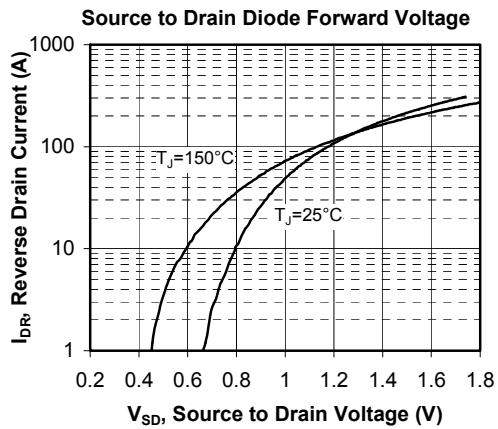
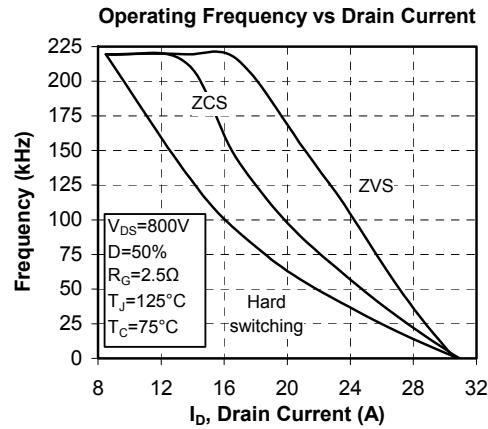
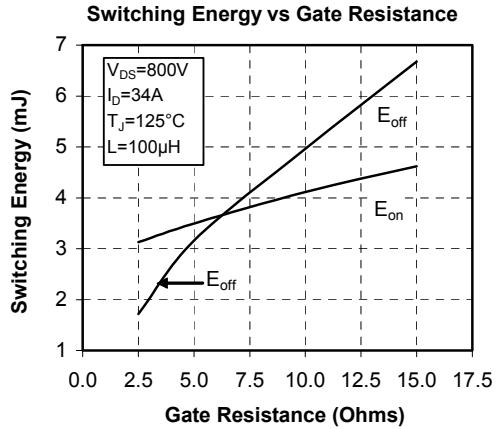
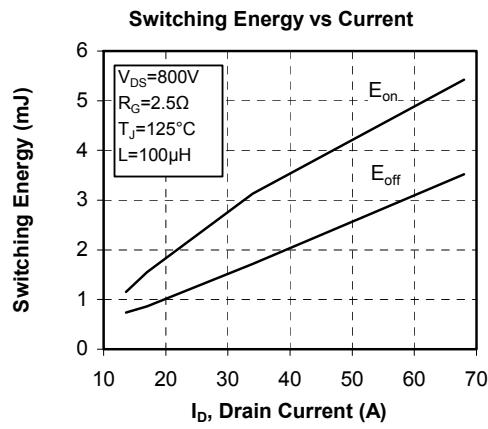
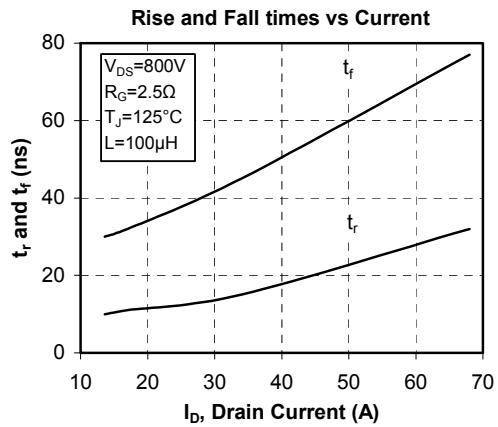
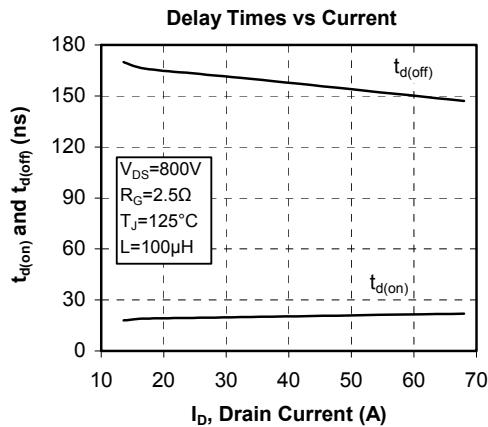
**Thermal and package characteristics**

Symbol	Characteristic		Min	Typ	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance			0.16		°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz		4000			V
$T_J$	Operating junction temperature range		-40		150	
$T_{STG}$	Storage Temperature Range		-40		125	°C
$T_C$	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink For terminals	M6 M5	3 2	5 3.5	N.m
Wt	Package Weight				300	g

**SP6 Package outline** (dimensions in mm)

 See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

**Typical Performance Curve**






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